

Application

- $\cdot \, \text{Motor drive}$
- · Inverter, Converter
- \cdot Photovoltaics, wind power generation.
- · Induction heating equipment.

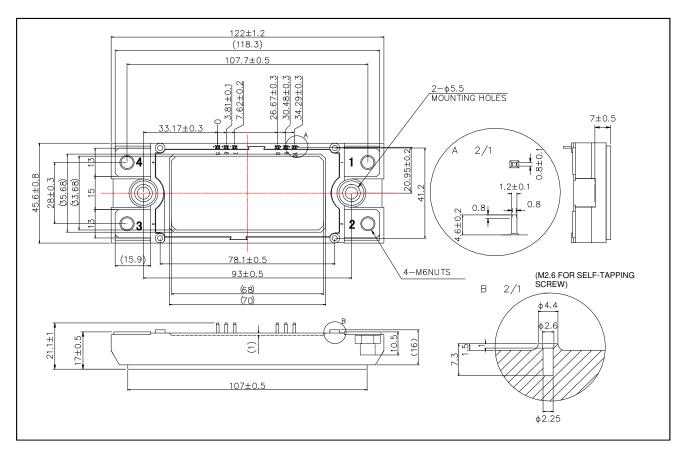
Features

- 1) Low surge, low switching loss.
- 2) High-speed switching possible.
- 3) Reduced temperature dependence.

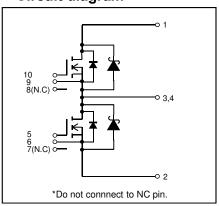
Construction

This product is a half bridge module consisting of SiC-UMOSFET and SiC-SBD from ROHM.

•Dimensions & Pin layout (Unit : mm)



Circuit diagram



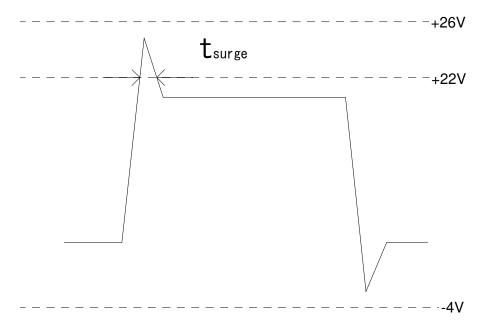
•Absolute maximum ratings $(T_j = 25^{\circ}C)$

Parameter	Symbol	Conditions	Limit	Unit	
Drain-source voltage	V _{DSS}	G-S short	1200		
Gate-source voltage(+)	V _{GSS}		22	V	
Gate-source voltage(-)		D-S short	-4		
G - S Voltage (t _{surge} <300ns)	V _{GSSsurge}		-4 to 26		
Drain current *1	Ι _D	DC (T _c =60°C)	180		
	I _{DRM}	Pulse (T _c =60°C) 1ms * ²	360		
	I _S	DC (T _c =60°C) V _{GS} =18V	180	A	
Source current * ¹	1	Pulse (T _c =60°C) 1ms V _{GS} =18V $*^2$	360		
	I _{SRM}	Pulse (T _c =60°C) 10 μ s V _{GS} =0V * ²	360	1	
Total power disspation * ³	Ptot	T _c =25°C	880	W	
Max Junction Temperature	T _{jmax}		175		
Junction temperature	T _{jop}		-40 to150	°C	
Storage temperature	T _{stg}		-40 to125		
Isolation voltage *4	Visol	Terminals to baseplate, f=60Hz AC 1min.	2500	Vrms	
Manuating a taxan a		Main Terminals : M6 screw	4.5	N·m	
Mounting torque	_	Mounting to heat shink : M5 screw	3.5		

(*1) Case temperature (T_c) is defined on the surface of base plate just under the chips.

(*2) Repetition rate should be kept within the range where temperature rise if die should not exceed $T_{jmax.}$ (*3) T_j is less than 175°C

Example of acceptable V_{GS} waveform



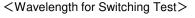
●Electrical characteristics (T_i=25°C)

Parameter	Symbol	Conditions		Min.	Тур.	Max.	Unit
Static drain-source on-state voltage	V _{DS(on)}	I _C =180A, V _{GS} =18V	T _j =25°C	-	1.8	2.6	v
			T _i =125°C	-	2.7	-	
			T _i =150°C	-	3.1	4	
Drain cutoff current	I _{DSS}	V _{DS} =1200V, V _{GS} =0V		-	-	2	mA
Source-drain voltage	V _{SD}	V _{GS} =0V, I _S =180A	T _j =25°C	-	2.1	2.6	V
			T _j =125°C		2.6	-	
			T _j =150°C	-	2.8	4.3	
		V _{GS} =18V, I _S =180A	T _j =25°C	-	1.4	-	
			T _j =125°C		1.9		
			T _j =150°C	-	2	-	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =10V, I _D =50mA		2.7	-	5.6	V
Gate-source leakage current	I _{GSS}	V_{GS} =22V, V_{DS} =0V		-	-	0.5	μA
		$V_{GS} = -6V, V_{DS} = 0V$		-0.5	-	-	
Switching characteristics	t _{d(on)}	$\label{eq:VGS(on)} \begin{split} &V_{GS(on)}{=}18V,V_{GS(off)}{=}-2V^{*4}\\ &V_{DS}{=}600V\\ &I_{D}{=}180A\\ &R_{G(on)}{=}8.2\Omega,R_{G(off)}{=}4.7\Omega\\ &\text{inductive load} \end{split}$		-	50	-	ns
	t _r			-	70	-	
	t _{rr}			-	35	-	
	$t_{d(off)}$			-	165	-	
	t _f			-	50	-	
Input capacitance	Ciss	V _{DS} =10V, V _{GS} =0V,200kHz		-	9	-	nF
Gate Registance	R _{Gint}	T _j =25°C		-	1.4	-	Ω
Stray Inductance	Ls				25.0	-	nH
Creepage Distance	-	Terminal to heat sink			11.5	-	mm
		Terminal to terminal			19.0	-	mm
Clearance Distance	-	Terminal to heat sink			9.5	-	mm
		Terminal to terminal			13.0	-	mm
Junction-to-case thermal	R _{th} (j-c)	UMOSFET (1/2 module) * ⁵		-	-	0.17	°C/W
resistance		SBD (1/2 module) *5		-	-	0.21	
Case-to-heat sink Thermal resistance	R _{th} (c-f)	Case to heat sink, per 1 module, Thermal grease applied * ⁶		-	0.035	-	°C/W

(*4) In order to prevent self turn-on, it is recommended to apply negative gate bias.

(*5) Measurement of Tc is to be done at the point just under the chip.

- (*6) Typical value is measured by using thermally conductive grease of λ =0.9W/(m · K).
- (*7) SiC devices have lower short cuicuit withstand capability due to high current density. Please be advised to pay careful attention to short cuicuit accident and try to adjust protection time to shutdown them as short as possible.
- (*8) If the Product is used beyond absolute maximum ratings defined in the Specifications, as its internal structure may be dameged, please replace such Product with a new one.



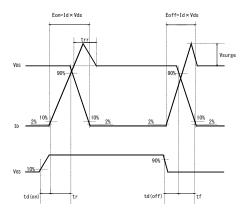


Fig.3 Drain-Source Voltage vs.

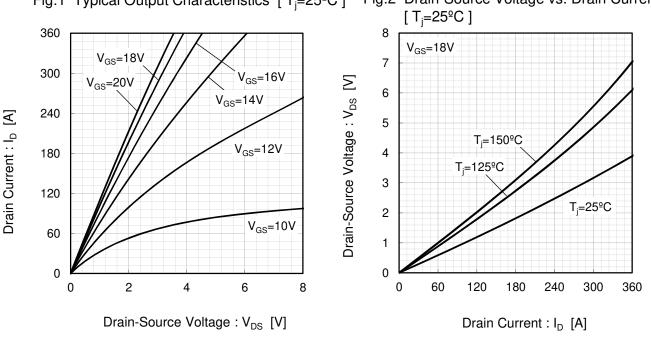
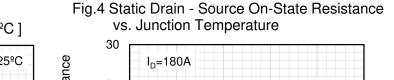
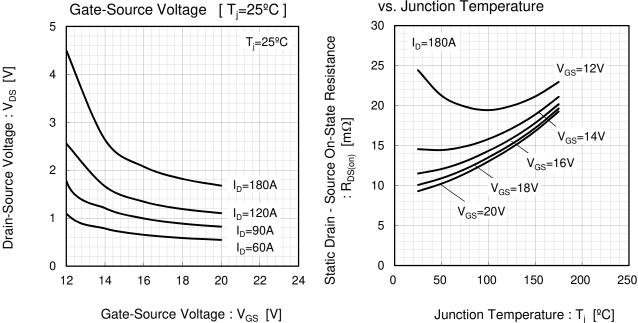


Fig.1 Typical Output Characteristics [Ti=25°C] Fig.2 Drain-Source Voltage vs. Drain Current





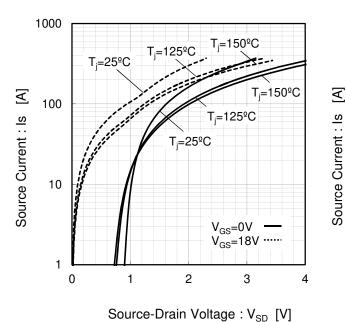
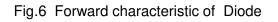
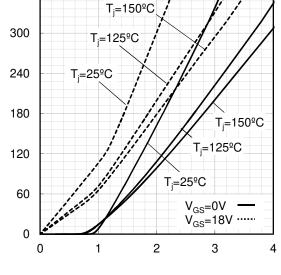


Fig.5 Forward characteristic of Diode



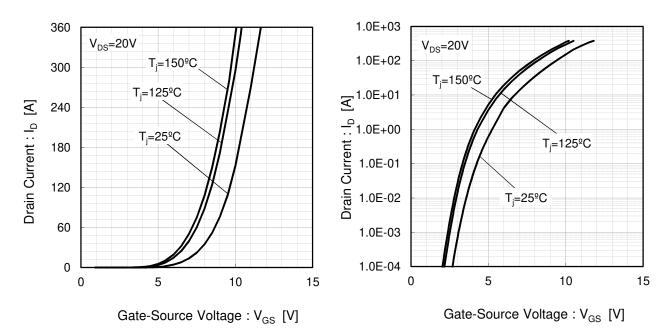
360



Source-Drain Voltage : V_{SD} [V]

Fig.7 Drain Current vs. Gate-Source Voltage

Fig.8 Drain Current vs. Gate-Source Voltage



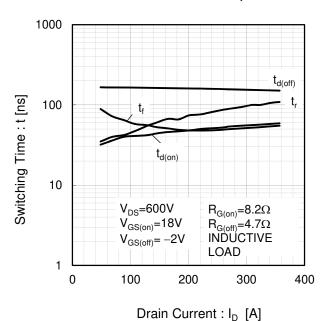


Fig.9 Switching Characteristics [T_i=25°C]

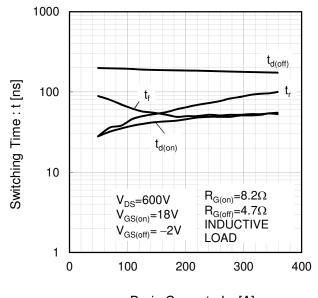
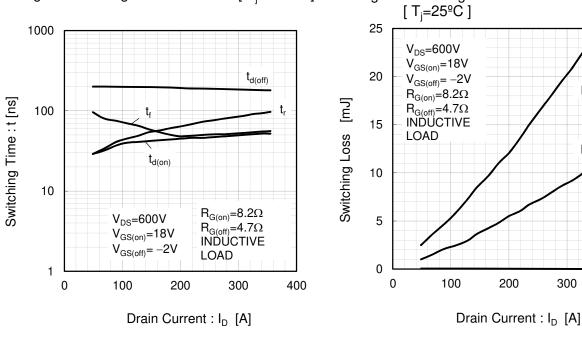


Fig.10 Switching Characteristics [T_i=125°C]

Drain Current : I_D [A]

Fig.12 Switching Loss vs. Drain Current

Fig.11 Switching Characteristics [T_i=150^oC]

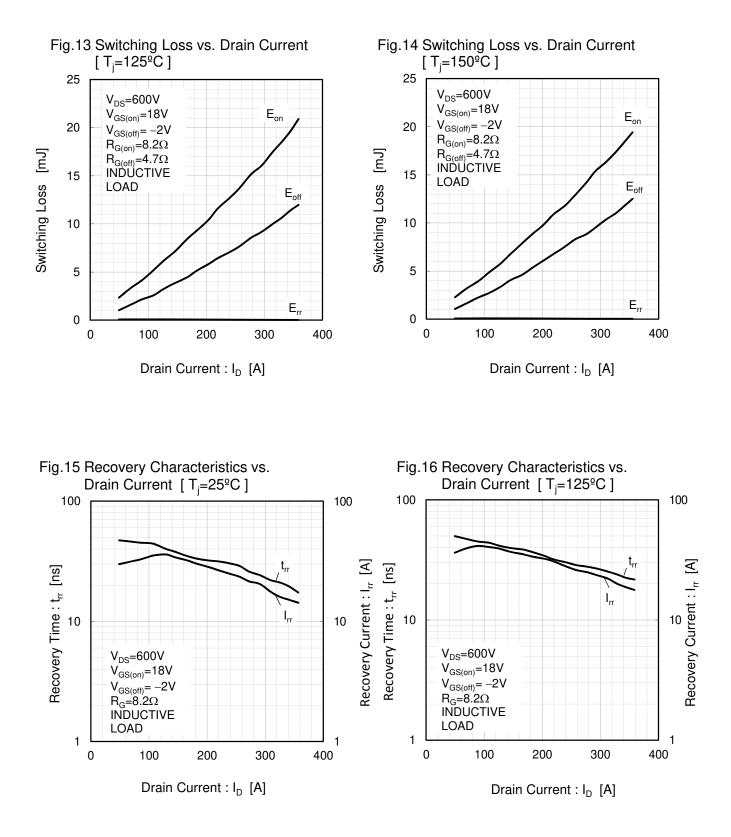


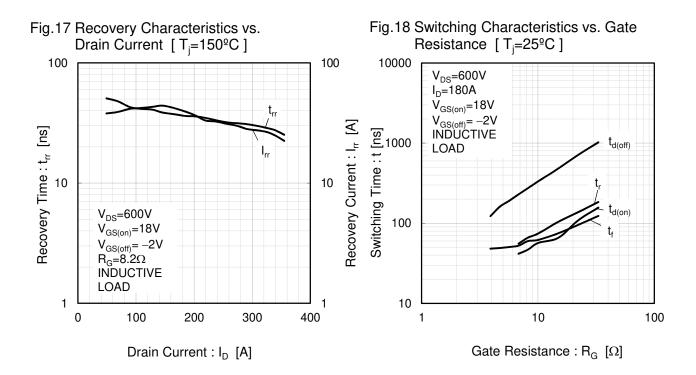
Eon

 $\mathsf{E}_{\mathsf{off}}$

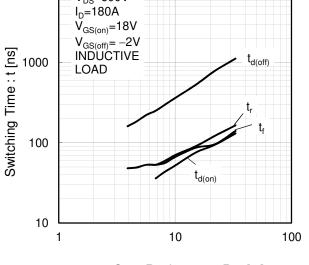
Err

400

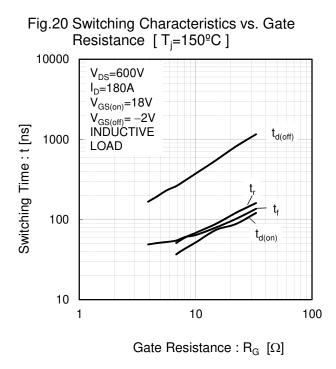


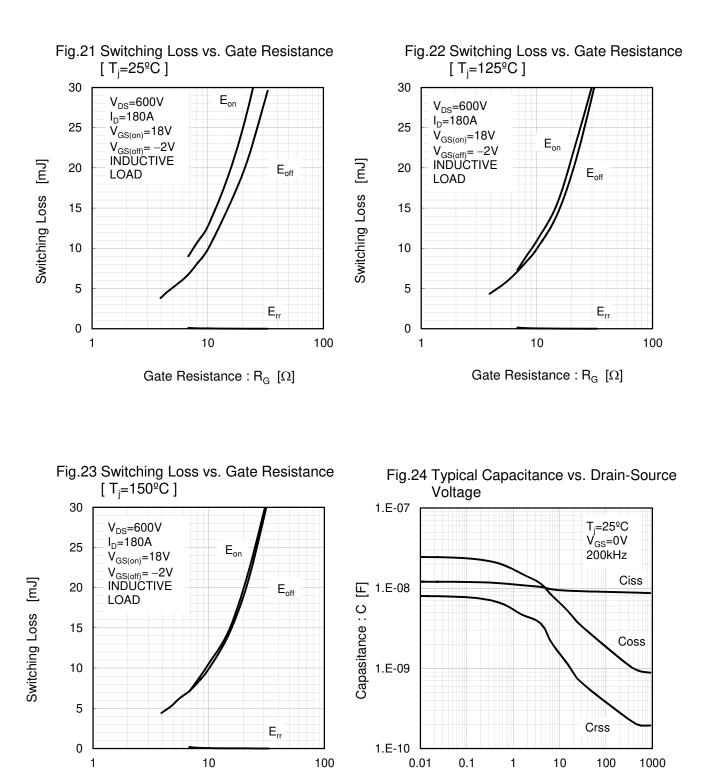


		haracteristics vs. Gate [T _j =125ºC]
10000	$V_{DS} = 600V$ $I_{D} = 180A$	



Gate Resistance : $R_G [\Omega]$

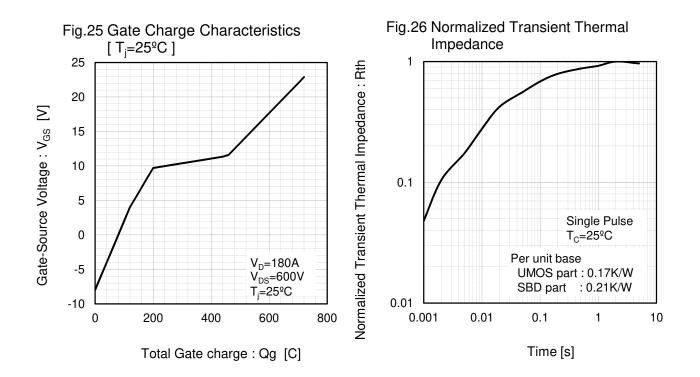




Drain-Source Voltage : V_{DS} [V]

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Gate Resistance : R_G [Ω]





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